



30V N-Channel Enhancement Mode MOSFET

Voltage

30 V

Current

70 A

Features

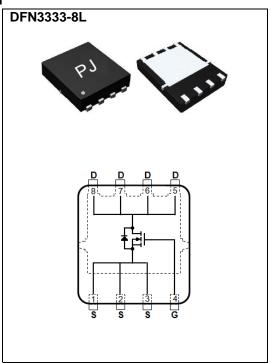
- R_{DS(ON)}, V_{GS}@10V, I_D@10A<3.8mΩ
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_{D}@5A<5.5m\Omega$
- High switching speed
- Improved dv/dt capability
- Low gate charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: DFN3333-8L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.001 ounces, 0.03 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

| PARAMETER | | SYMBOL | LIMIT | UNITS | |
|--------------------------------------------------|----------------------|----------------------------------|-------------|-------|--|
| Drain-Source Voltage | | V _{DS} | 30 | V | |
| Gate-Source Voltage | | V _{GS} | <u>+</u> 20 | | |
| Continuous Drain Current | Tc=25°C | I _D | 70 | A | |
| | Tc=100°C | | 44 | | |
| Pulsed Drain Current(Note 1) | Tc=25°C | I _{DM} | 280 | | |
| Power Dissipation | Tc=25°C | Po | 39 | W | |
| | Tc=100°C | | 15.6 | | |
| Continuous Drain Current | T _A =25°C | l _D | 16 | А | |
| | T _A =70°C | | 13 | | |
| Power Dissipation | T _A =25°C | | 2.0 | 107 | |
| Power Dissipation | T _A =70°C | Pb | 1.3 | W | |
| Operating Junction and Storage Temperature Range | | T _J ,T _{STG} | -55~150 | °C | |
| Typical Thermal Resistance ^(Note 4,5) | Junction to Case | R _{0JC} | 3.21 | | |
| | Junction to Ambient | $R_{	heta JA}$ | 62.5 | °C/W | |

• Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25°C unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS |
|----------------------------------|---------------------|------------------------------------------------------------------------------------------------------|------|------|--------------|-------|
| Static | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V, I _D =250uA | 30 | - | - | V |
| Gate Threshold Voltage | $V_{GS(th)}$ | V _{DS} =V _{GS} , I _D =250uA | 1 | 1.6 | 2.5 | |
| Drain-Source On-State Resistance | R _{DS(on)} | V _{GS} =10V, I _D =10A | - | 3.3 | 3.8 | mΩ |
| | | V _{GS} =4.5V, I _D =5A | - | 5.0 | 5.5 | |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =30V, V _{GS} =0V | - | - | 1 | uA |
| Gate-Source Leakage Current | Igss | V _{GS} = <u>+</u> 20V, V _{DS} =0V | - | - | <u>+</u> 100 | nA |
| Dynamic ^(Note 6) | | | | | | |
| Total Gate Charge | Q_g | V _{DS} =15V, I _D =24A, V _{GS} =4.5V ^(Note 2,3) | - | 23 | - | nC |
| Gate-Source Charge | Q_{gs} | | - | 8 | - | |
| Gate-Drain Charge | Q_gd | | - | 9 | - | |
| Input Capacitance | Ciss | V _{DS} =25V, V _{GS} =0V, f=1.0MHZ | - | 2436 | - | pF |
| Output Capacitance | Coss | | - | 306 | - | |
| Reverse Transfer Capacitance | Crss | I=1.0IVII 1Z | - | 196 | - | |
| Turn-On Delay Time | td _(on) | \/ 45\/ 45\ | - | 32 | - | |
| Turn-On Rise Time | tr | V _{DS} =15V, I _D =15A, V _{GS} =10V, R _G =1Ω (Note 2,3) | - | 169 | - | ns |
| Turn-Off Delay Time | td _(off) | | - | 232 | - | |
| Turn-Off Fall Time | t _f | (************************************** | - | 170 | - | |
| Drain-Source Diode | | | _ | | | |
| Maximum Continuous Drain-Source | Is | | - | - | 70 | А |
| Diode Forward Current | IŞ | | | | | |
| Diode Forward Voltage | V_{SD} | I _S =1A, V _{GS} =0V | - | 0.66 | 1.0 | V |

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics
- 3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper
- 6. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

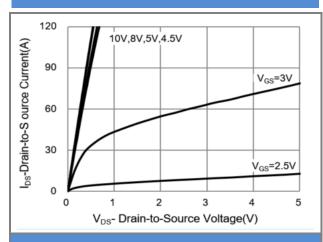


Fig.1 On-Region Characteristics

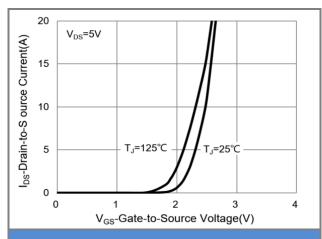


Fig.2 Transfer Characteristics

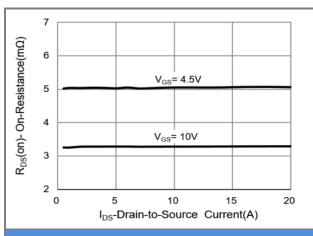


Fig.3 On-Resistance vs. Drain Current

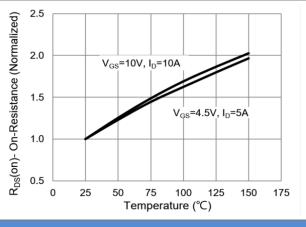


Fig.4 On-Resistance vs. Junction temperature

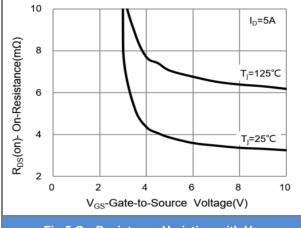


Fig.5 On-Resistance Variation with V_{GS}

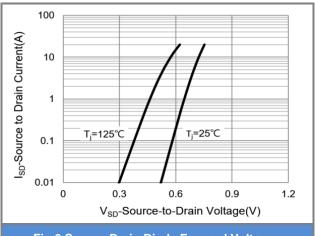


Fig.6 Source-Drain Diode Forward Voltage





TYPICAL CHARACTERISTIC CURVES

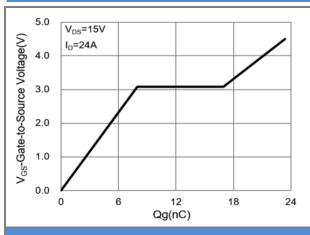


Fig.7 Gate-Charge Characteristics

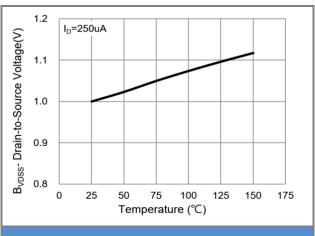


Fig.8 Breakdown Voltage Variation vs. Temperature

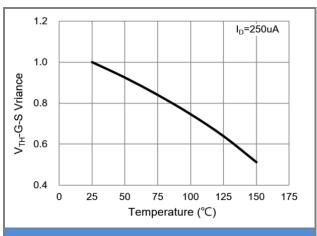


Fig.9 Threshold Voltage Variation with Temperature

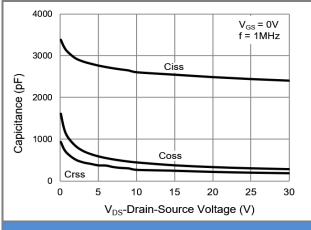
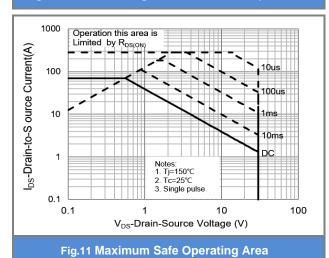


Fig.10 Capacitance vs. Drain-Source Voltage



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TYPICAL CHARACTERISTIC CURVES

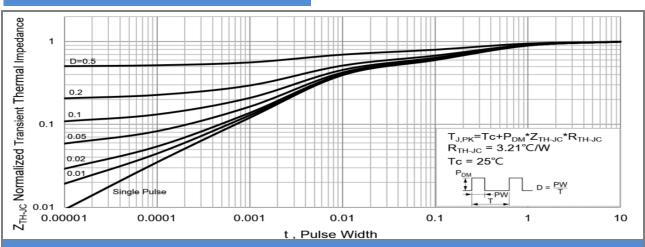


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

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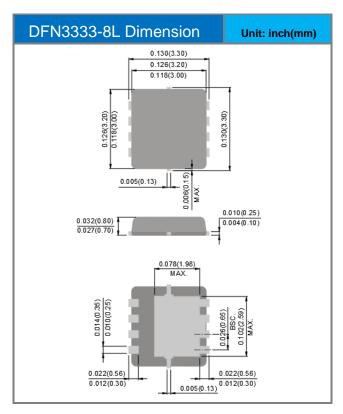


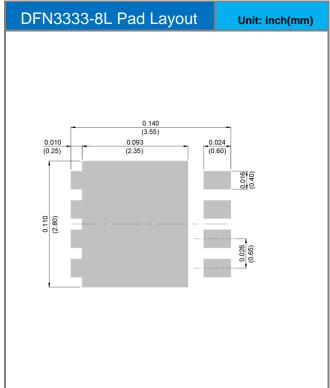


Part No. Packing Code Version

| Part No. Packing Code | Package Type | Packing Type | Marking | Version |
|-----------------------|--------------|-------------------|---------|--------------------------------|
| PJQ4402P_R2_00001 | DFN3333-8L | 5K pcs / 13" reel | 4402 | Halogen free RoHS compliant |

Packaging Information & Mounting Pad Layout









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